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# FCP22N60N / FCPF22N60NT

## N-Channel SupreMOS® MOSFET

### 600 V, 22 A, 165 mΩ

#### Features

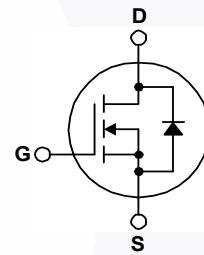
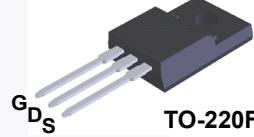
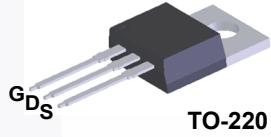
- $BV_{DSS} > 650$  V @  $T_J = 150^\circ\text{C}$
- $R_{DS(on)} = 140$  mΩ (Typ.) @  $V_{GS} = 10$  V,  $I_D = 11$  A
- Ultra Low Gate Charge (Typ.  $Q_g = 45$  nC)
- Low Effective Output Capacitance (Typ.  $C_{oss(\text{eff.})} = 196.4$  pF)
- 100% Avalanche Tested
- RoHS Compliant

#### Application

- LCD/LED/PDP TV
- Lighting
- Solar Inverter
- AC-DC Power Supply

#### Description

The SupreMOS® MOSFET is Fairchild Semiconductor's next generation of high voltage super-junction (SJ) technology employing a deep trench filling process that differentiates it from the conventional SJ MOSFETs. This advanced technology and precise process control provides lowest  $R_{sp}$  on-resistance, superior switching performance and ruggedness. SupreMOS MOSFET is suitable for high frequency switching power converter applications such as PFC, server/telecom power, FPD TV power, ATX power, and industrial power applications.



**Absolute Maximum Ratings**  $T_C = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter		FCP22N60N	FCPF22N60NT	Unit
$V_{DSS}$	Drain to Source Voltage		600		V
$V_{GSS}$	Gate to Source Voltage		$\pm 45$		V
$I_D$	Drain Current	- Continuous ( $T_C = 25^\circ\text{C}$ )	22	22*	A
		- Continuous ( $T_C = 100^\circ\text{C}$ )	13.8	13.8*	
$I_{DM}$	Drain Current	- Pulsed (Note 1)	66	66*	A
$E_{AS}$	Single Pulsed Avalanche Energy (Note 2)		672		mJ
$I_{AR}$	Avalanche Current (Note 1)		7.3		A
$E_{AR}$	Repetitive Avalanche Energy (Note 1)		2.75		mJ
$dv/dt$	MOSFET $dv/dt$		100		V/ns
	Peak Diode Recovery $dv/dt$ (Note 3)		20		
$P_D$	Power Dissipation	( $T_C = 25^\circ\text{C}$ )	205	39	W
		- Derate Above $25^\circ\text{C}$	1.64	0.31	W/ $^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature Range		-55 to +150		$^\circ\text{C}$
$T_L$	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300		$^\circ\text{C}$

\*Drain current limited by maximum junction temperature.

#### Thermal Characteristics

Symbol	Parameter	FCP22N60N	FCPF22N60NT	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.61	3.2	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	62.5	$^\circ\text{C/W}$

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCP22N60N	FCP22N60N	TO-220	Tube	N/A	N/A	50 units
FCPF22N60NT	FCPF22N60NT	TO-220F	Tube	N/A	N/A	50 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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### Off Characteristics

$\text{BV}_{\text{DSS}}$	Drain to Source Breakdown Voltage	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}, T_J = 25^\circ\text{C}$	600	-	-	V
		$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}, T_J = 150^\circ\text{C}$	650	-	-	
$\Delta \text{BV}_{\text{DSS}} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 1 \text{ mA}$ , Referenced to $25^\circ\text{C}$	-	0.68	-	$\text{V}/^\circ\text{C}$
		$V_{DS} = 480 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	10	
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{DS} = 480 \text{ V}, T_J = 125^\circ\text{C}$	-	-	100	$\mu\text{A}$
		$V_{GS} = \pm 45 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	$\pm 100$	
$I_{\text{GSS}}$	Gate to Body Leakage Current	$V_{GS} = \pm 45 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	-	nA

### On Characteristics

$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	2.0	3.0	4.0	V
$R_{DS(\text{on})}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 11 \text{ A}$	-	0.140	0.165	$\Omega$
$g_{\text{FS}}$	Forward Transconductance	$V_{DS} = 20 \text{ V}, I_D = 11 \text{ A}$	-	22	-	S

### Dynamic Characteristics

$C_{\text{iss}}$	Input Capacitance	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	1950	-	pF
$C_{\text{oss}}$	Output Capacitance		-	75.9	-	pF
$C_{\text{rss}}$	Reverse Transfer Capacitance		-	3	-	pF
$C_{\text{oss}}$	Output Capacitance	$V_{DS} = 380 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	43.2	-	pF
$C_{\text{oss(eff.)}}$	Effective Output Capacitance	$V_{DS} = 0 \text{ V} \text{ to } 480 \text{ V}, V_{GS} = 0 \text{ V}$	-	196.4	-	pF
$Q_{\text{g(tot)}}$	Total Gate Charge at 10V	$V_{DS} = 380 \text{ V}, I_D = 11 \text{ A}, V_{GS} = 10 \text{ V}$	-	45	-	nC
$Q_{\text{gs}}$	Gate to Source Gate Charge		-	8.7	-	nC
$Q_{\text{gd}}$	Gate to Drain "Miller" Charge		-	14.5	-	nC
ESR	Equivalent Series Resistance (G-S)	$f = 1 \text{ MHz}$	-	1	-	$\Omega$

### Switching Characteristics

$t_{\text{d(on)}}$	Turn-On Delay Time	$V_{DD} = 380 \text{ V}, I_D = 11 \text{ A}$ $V_{GS} = 10 \text{ V}, R_G = 4.7 \Omega$	-	16.9	-	ns
$t_r$	Turn-On Rise Time		-	16.7	-	ns
$t_{\text{d(off)}}$	Turn-Off Delay Time		-	49	-	ns
$t_f$	Turn-Off Fall Time		(Note 4)	-	4	-

### Drain-Source Diode Characteristics

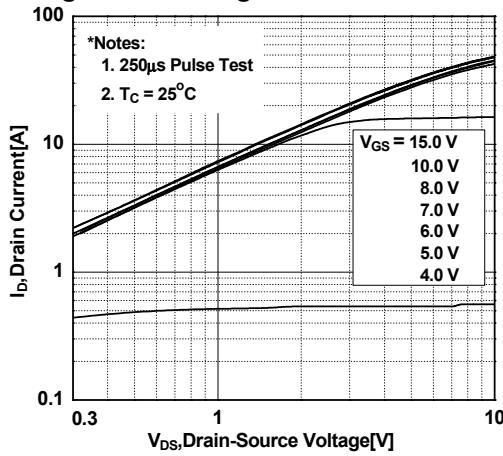
$I_S$	Maximum Continuous Drain to Source Diode Forward Current	-	-	22	A	
$I_{\text{SM}}$	Maximum Pulsed Drain to Source Diode Forward Current	-	-	66	A	
$V_{\text{SD}}$	Drain to Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{SD} = 11 \text{ A}$	-	-	1.2	V
$t_{\text{rr}}$	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_{SD} = 11 \text{ A}$	-	350	-	ns
$Q_{\text{rr}}$	Reverse Recovery Charge	$dl_F/dt = 100 \text{ A}/\mu\text{s}$	-	6	-	$\mu\text{C}$

#### Notes:

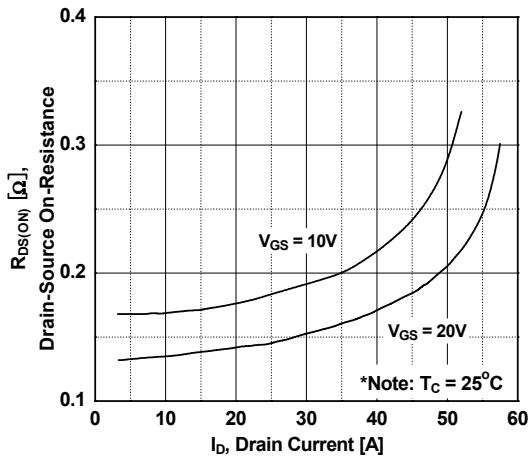
1. Repetitive rating: pulse width-limited by maximum junction temperature.
2.  $I_{AS} = 7.3 \text{ A}$ ,  $R_G = 25 \Omega$ , starting  $T_J = 25^\circ\text{C}$ .
3.  $I_{SD} \leq 22 \text{ A}$ ,  $di/dt \leq 200 \text{ A}/\mu\text{s}$ ,  $V_{DD} \leq 380 \text{ V}$ , starting  $T_J = 25^\circ\text{C}$ .
4. Essentially independent of operating temperature typical characteristics.

## Typical Performance Characteristics

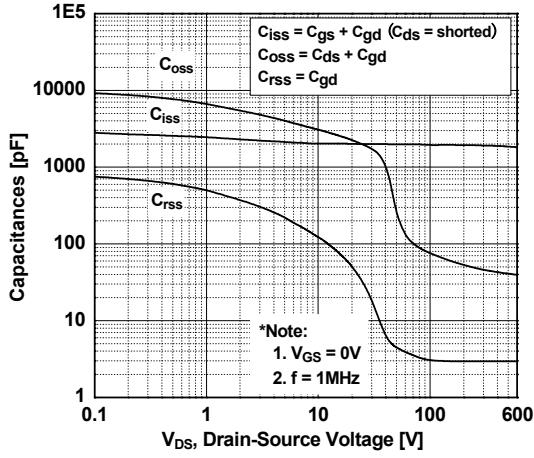
**Figure 1. On-Region Characteristics**



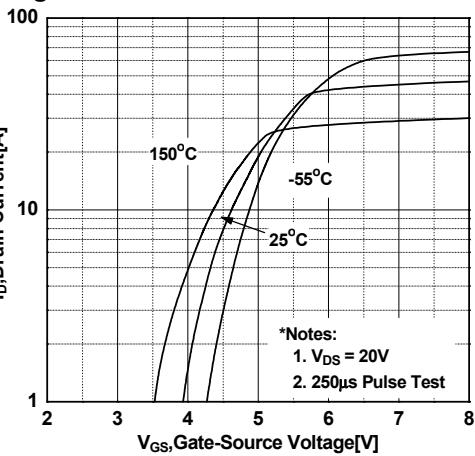
**Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage**



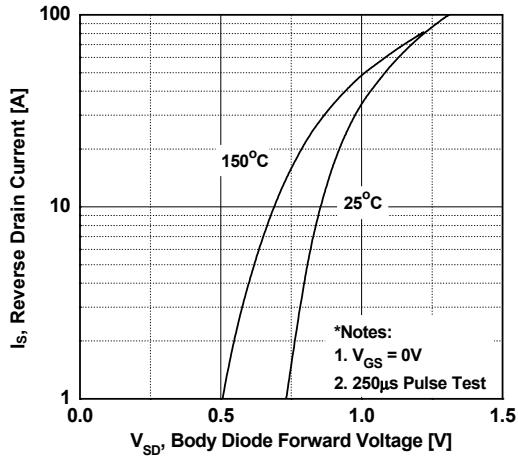
**Figure 5. Capacitance Characteristics**



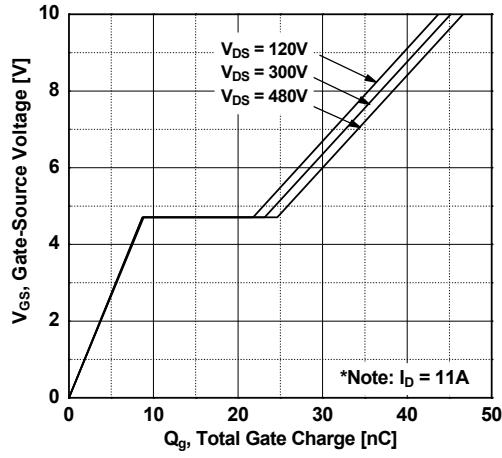
**Figure 2. Transfer Characteristics**



**Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature**

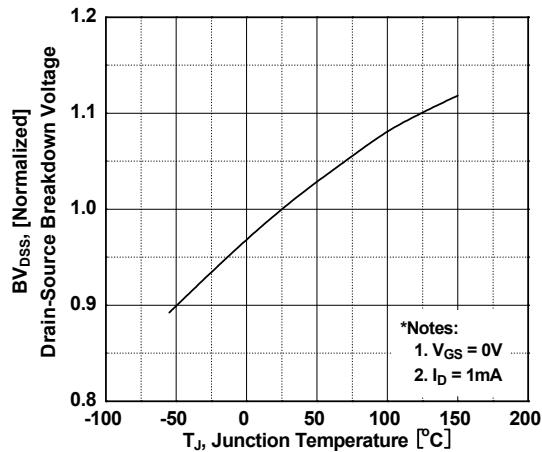


**Figure 6. Gate Charge Characteristics**

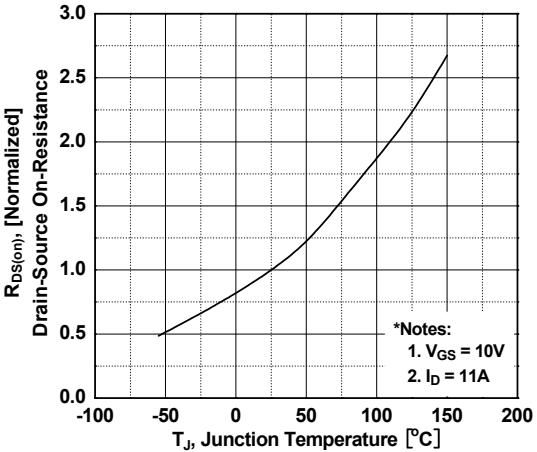


## Typical Performance Characteristics (Continued)

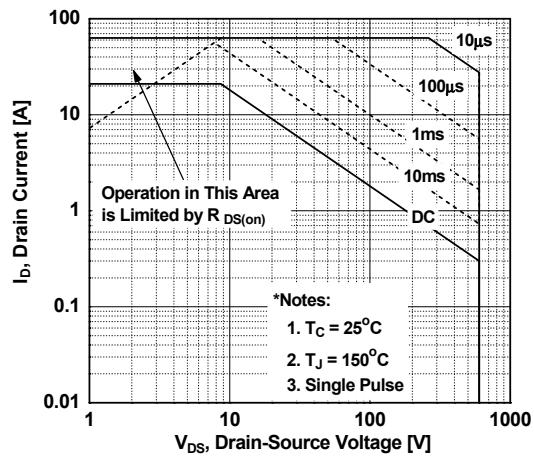
**Figure 7. Breakdown Voltage Variation vs. Temperature**



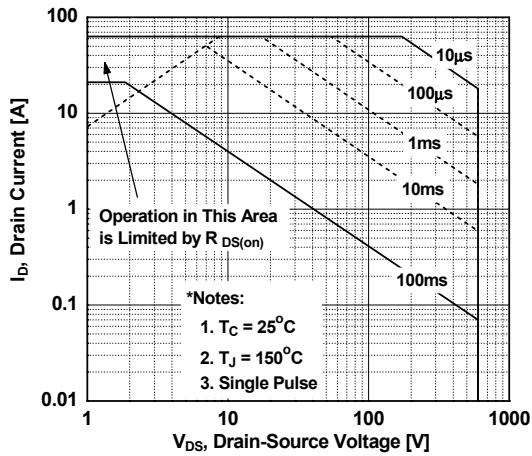
**Figure 8. On-Resistance Variation vs. Temperature**



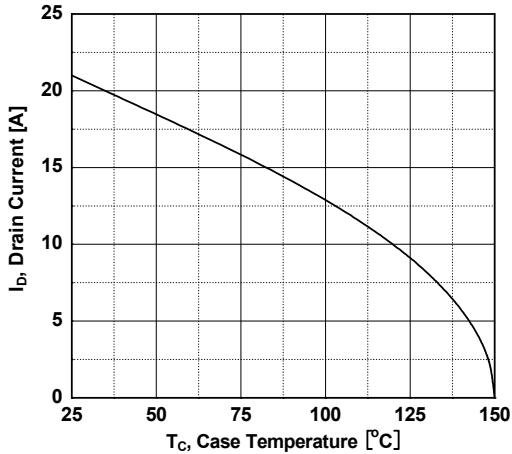
**Figure 9. Maximum Safe Operating Area for FCP22N60N**



**Figure 10. Maximum Safe Operating Area for FCPF22N60NT**



**Figure 11. Maximum Drain Current vs. Case Temperature**



## Typical Performance Characteristics (Continued)

Figure 12. Transient Thermal Response Curve for FCP22N60N

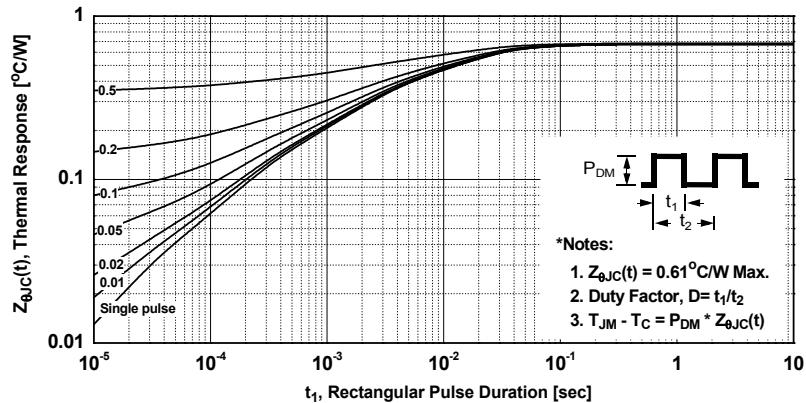
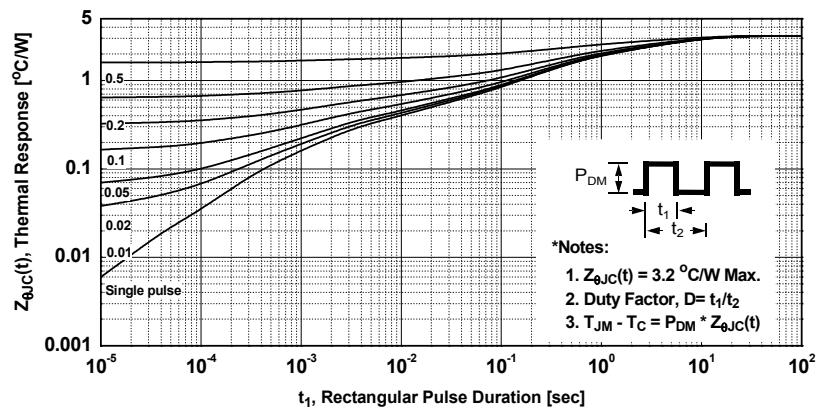


Figure 13. Transient Thermal Response Curve for FCPF22N60NT



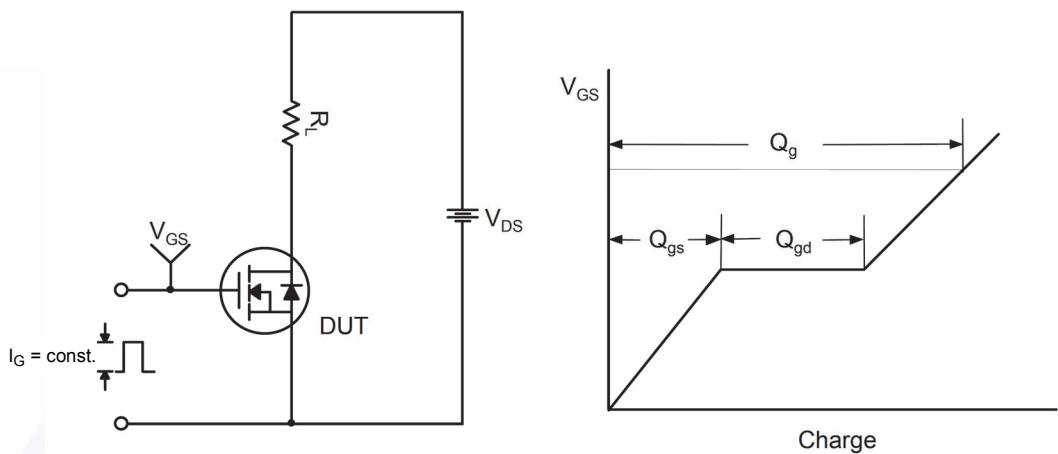


Figure 14. Gate Charge Test Circuit & Waveform

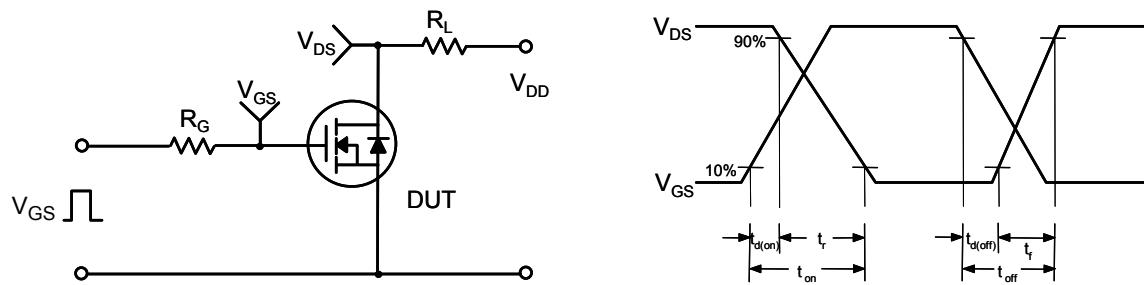


Figure 15. Resistive Switching Test Circuit & Waveforms

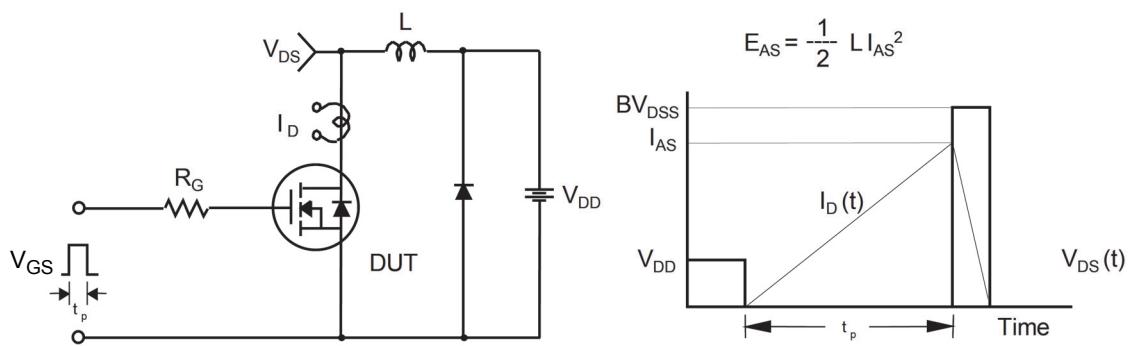


Figure 16. Unclamped Inductive Switching Test Circuit & Waveforms

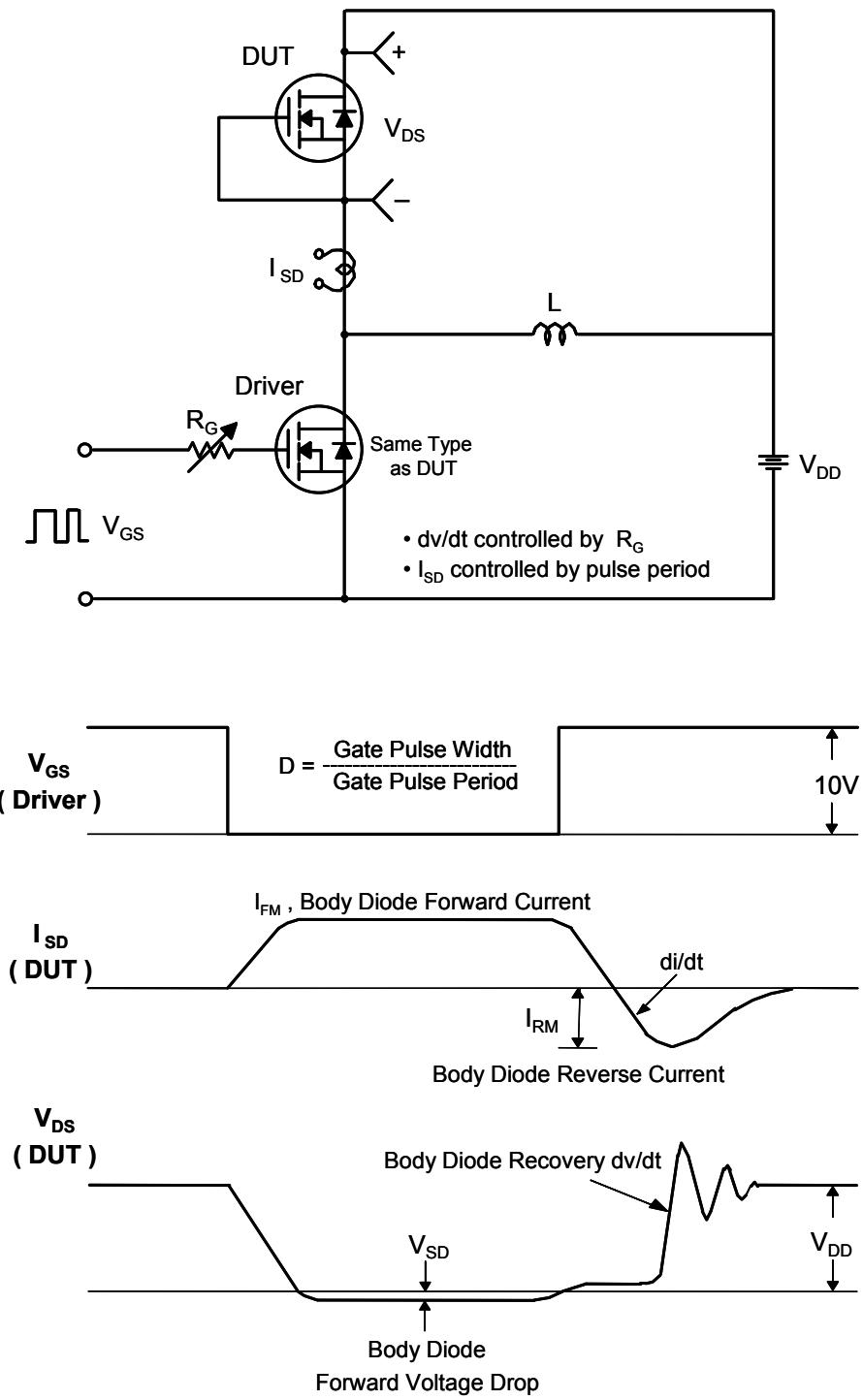
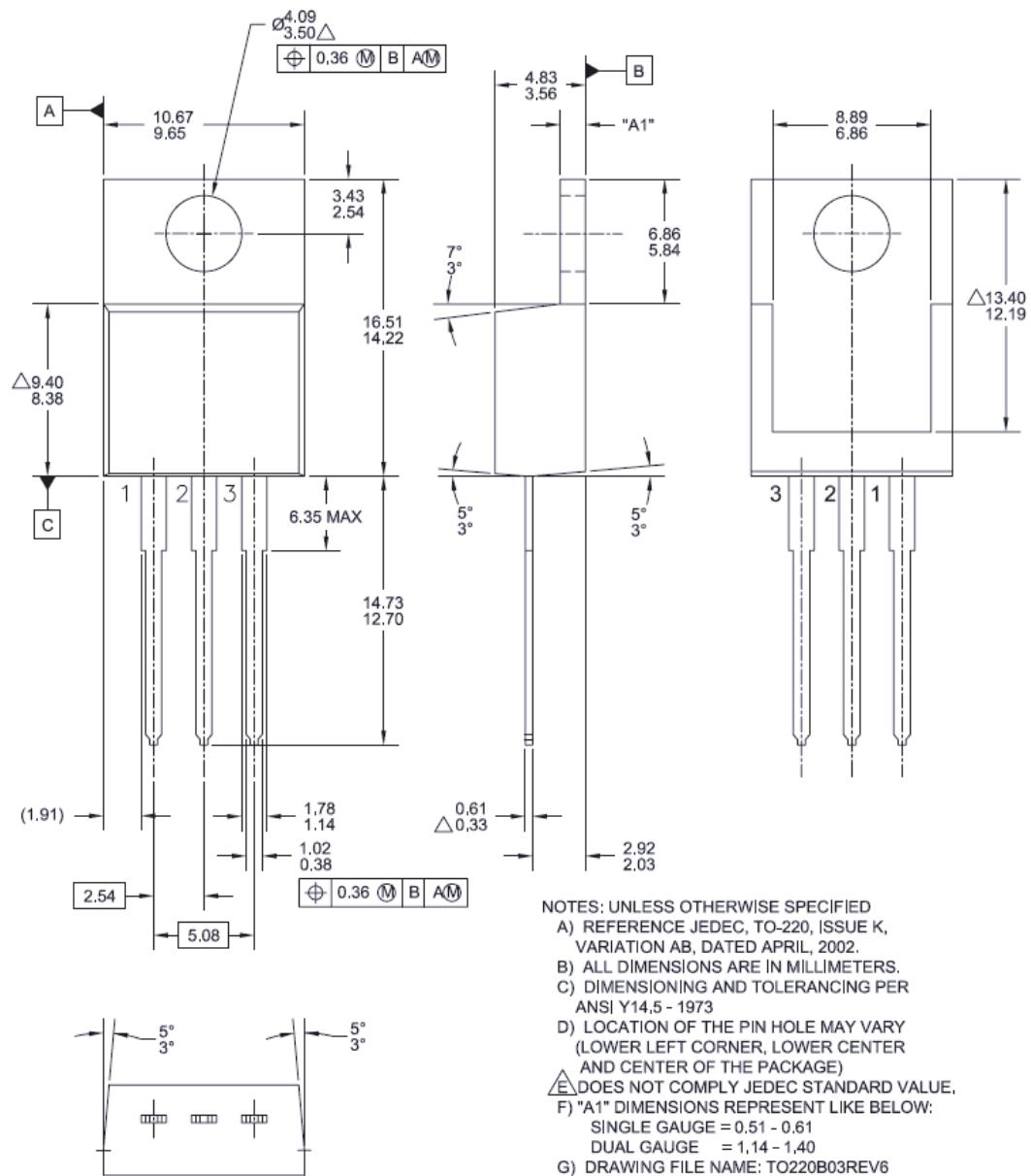


Figure 17. Peak Diode Recovery  $dv/dt$  Test Circuit & Waveforms

## Mechanical Dimensions



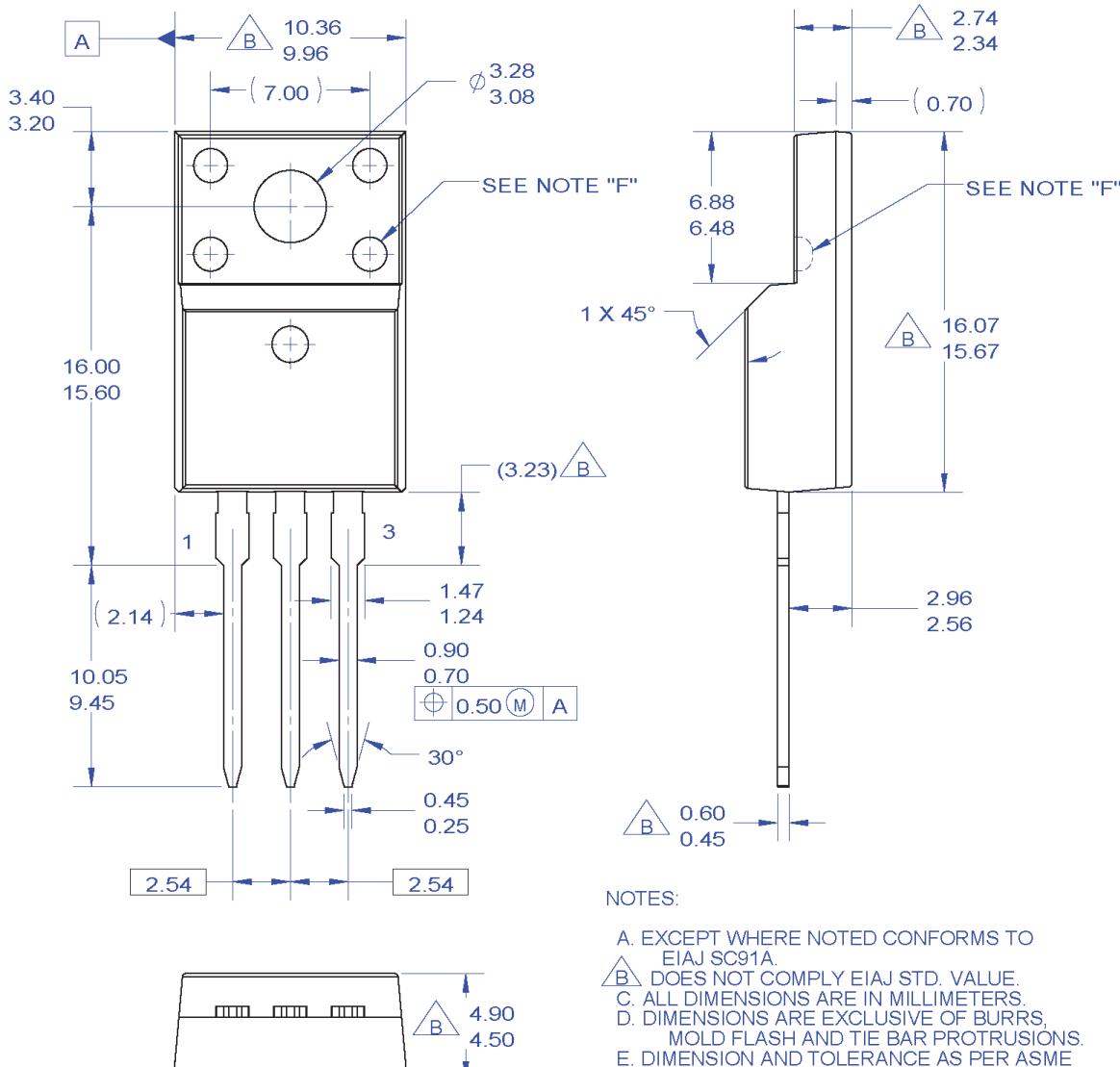
**Figure 18. TO-220, Molded, 3-Lead, Jedec Variation AB**

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## Mechanical Dimensions



**Figure 19. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead**

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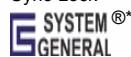
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